

# PUMH1

# NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

5 February 2024

**Product data sheet** 

# 1. General description

NPN/NPN Resistor-Equipped double Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

# 3. Applications

- Low current peripheral driver
- Control of IC inputs
- · Replaces general-purpose transistors in digital applications

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.



NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1		
3	O2	output (collector) TR2	6 5 4	R1     R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		TR1 R2 R1
6	O1	output (collector) TR1	□1 □2 □3 TSSOP6 (SOT363)	GND1 I1 O2 aaa-019894

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package				
	Name	Description	Version		
PUMH1		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>		

# 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH1	Н%2

[1] % = placeholder for manufacturing site code

NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

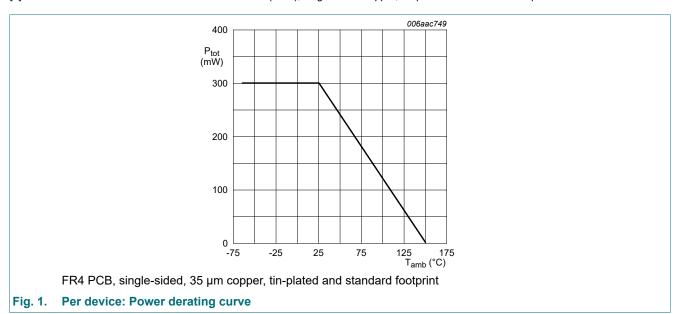
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or			'		
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
VI	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
Per device				'		'
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

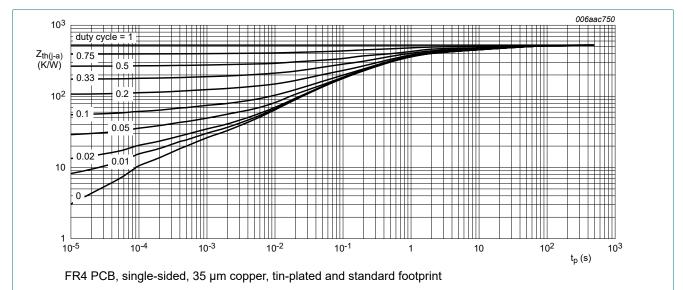


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

# 10. Characteristics

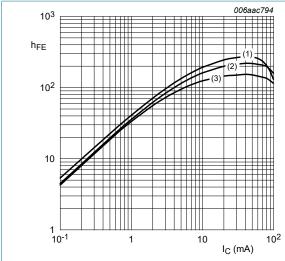
**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	T <sub>amb</sub> = 25 °C		50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	= 0 A; I <sub>E</sub> = 100 A; T <sub>amb</sub> = 25 °C		10	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
SES	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 150 °C		-	-	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	180	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C		60	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	150	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-	1.1	0.8	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V; } I_{C} = 5 \text{ mA; } T_{amb} = 25 \text{ °C}$		2.5	1.7	-	V
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	230	-	MHz

<sup>[1]</sup> See section "Test information" for resistor calculation and test conditions.

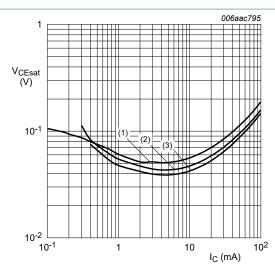
<sup>[2]</sup> Characteristics of built-in transistor

#### NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$



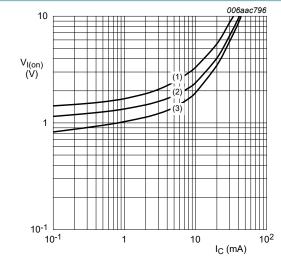
V<sub>CE</sub> = 5 V (1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -40 °C

Fig. 3. DC current gain as a function of collector current; typical values



 $I_{C}/I_{B} = 20$ (1)  $T_{amb} = 100 \, ^{\circ}C$ (2)  $T_{amb} = 25 \, ^{\circ}C$ (3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

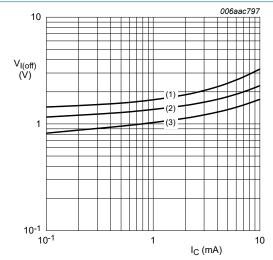


 $V_{CE}$  = 0.3 V

(1)  $T_{amb} = -40 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 





 $V_{CE} = 5 V$ 

(1)  $T_{amb} = -40 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Off-state input voltage as a function of collector current; typical values

### NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

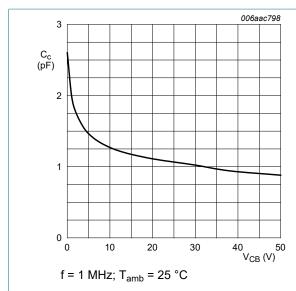


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

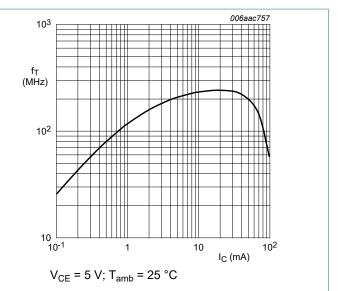


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

# 11. Test information

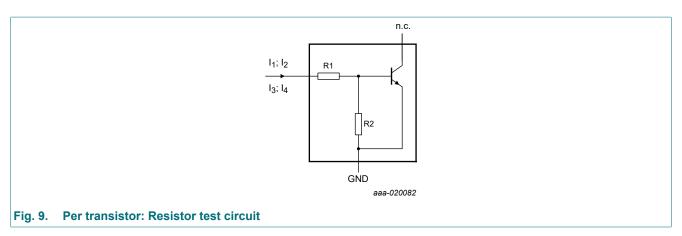
#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

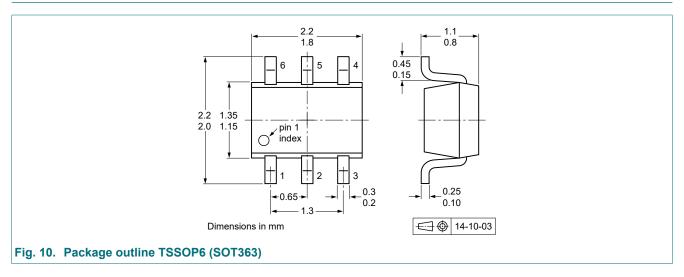


#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14
PUMH1	22	22	150 μΑ	230 μΑ	-150 μA	-230 µA

# 12. Package outline

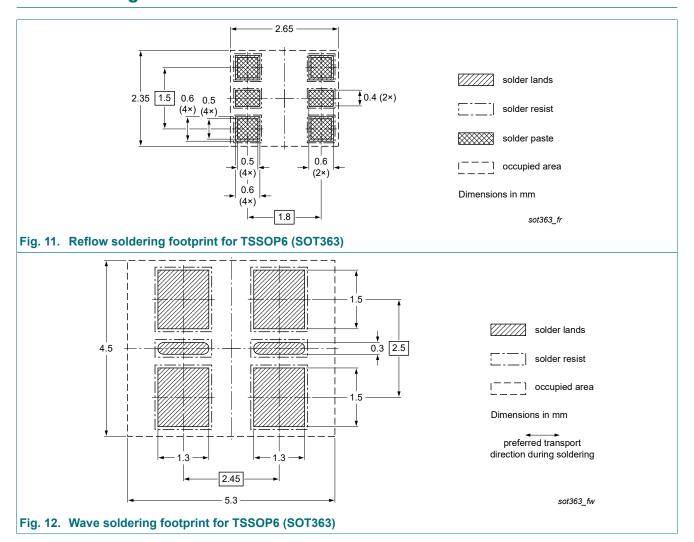


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### NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

# 13. Soldering



## NPN/NPN resistor-equipped double transistor; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

# 14. Revision history

#### Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH1 v.7	20221114	Product data sheet	-	PUMH1 v.6
Modifications:	` ,	ed to non-automotive qualifi roduct alternative(s).	cation. Please refer to	o nexperia.com for
PUMH1 v.6	20221114	Product data sheet	-	PEMH1_PUMH1 v.5
PEMH1_PUMH1 v.5	20111202	Product data sheet	-	PEMH1_PUMH1 v.4
PEMH1_PUMH1 v.4	20031008	Product data sheet	-	PEMH1 v.1 PUMH1 v.3
PEMH1 v.1	20011022	Preliminary data sheet	-	-
PUMH1 v.3	19990520	Product specification	-	-
PUMH1 v.2	19980806	Product specification	-	PUMH1 v.1
PUMH1 v.1	19971212	Product specification	-	-

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## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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